

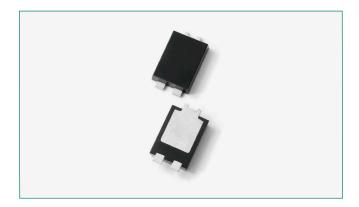
DST580S-A



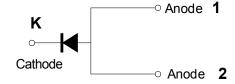








Pin out



Description

Littelfuse DST series Ultra Low V_E Schottky Barrier Rectifier is designed to meet the general requirements of automotive applications by providing high temperature, low leakage and lower V_E products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- High reliability application and AEC-Q101 qualified
- Ultra low forward voltage
- High frequency operation
- MSL: Level 1 unlimited
- High junction temperature capability
- Trench MOS Schottky technology

- Single die in TO-277B Package
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Applications

- Switching mode power
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V _{RWM}	-	80	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _L = 125 °C rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	80	А

Electrical Characteristics

Parameters	Symbol	Test Conditions	Тур	Max	Unit	
	V	@2.5A, Pulse, T _J = 25 °C	0.48	-		
Forward Voltage Drop*	V _{F1}	@5A, Pulse, T _J = 25 °C	0.59	0.72	V	
roi watu voitage Diop		@2.5A, Pulse, T _J = 125 °C	0.45	-	V	
	V _{F2}	@5A, Pulse, T _J = 125 °C	0.59	0.66		
Reverse Current*	I _{R1}	$@V_R = rated V_R, T_J = 25 °C$	0.011	0.4	mA	
neverse Current	I _{R2}	$@V_R = rated V_{R_i} T_J = 125 ^{\circ}C$	4	15	- IIIA	
Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	245	-	pF	

^{*} Pulse Width < 300µs, Duty Cycle <2%



Thermal-Mechanical Specifications					
Parameters	Symbol	Test Conditions	Max	Unit	
Junction Temperature	T _J		-55 to +150	°C	
Storage Temperature	T _{stg}		-55 to +150	°C	
Maximum Thermal Resistance Junction to Ambient	R _{thJA}	DC eneration	75	°C/W	
Maximum Thermal Resistance Junction to Lead	R _{thJL}	DC operation	4	°C/W	
Approximate Weight	wt		0.08	g	
Case Style	TO-277B				

Figure 1: Typical Forward Characteristics

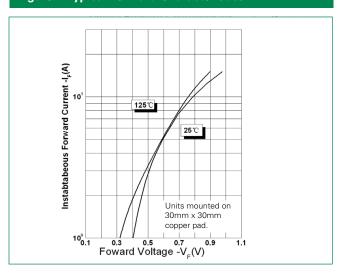


Figure 2: Typical Reverse Characteristics

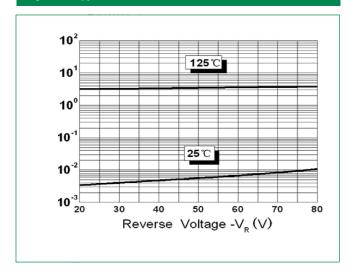
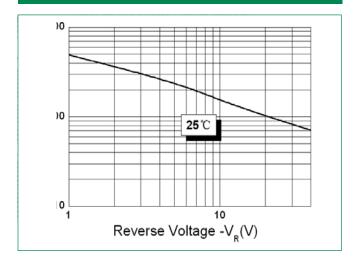
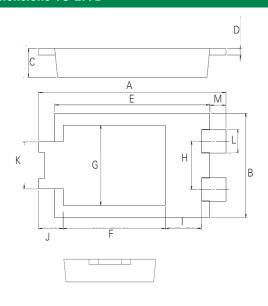


Figure 3: Typical Junction Capacitance



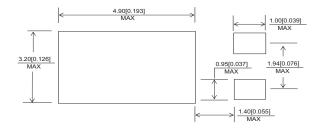


Dimensions-TO-277B



Symbol	Millimeters			
Symbol	Min	Тур	Max	
А	6.30	6.50	6.70	
В	3.88	3.98	4.08	
С	0.95	1.10	1.25	
D	0.20	0.25	0.30	
E	5.28	5.38	5.48	
F	3.40	3.55	3.70	
G	2.90	3.05	3.20	
Н	1.74	1.84	1.94	
I	1.10	1.25	1.40	
J	-	0.85	-	
K	1.70	1.80	1.90	
L	0.85	0.90	0.95	
М	-	0.56	-	

Mounting Pad Layout



Packing Options

Part Number	Marking	Packing Mode	M.O.Q	
DST580S-A	DST580S-A	5000pcs / Reel	5000	

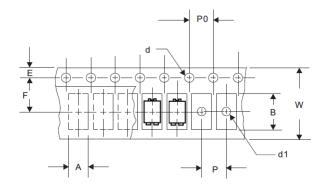
Part Numbering and Marking System



DST = Device Type
5 = Forward Current (5A)
80 = Reverse Voltage (80V)
S = Package Type
A = AEC-Q101 qualified device
LF = Littelfuse
YY = Year

WW = Week
L = Lot Number

Carrier Tape & Reel Specification



Symbol	Millimeters		
Cymbol	Min	Max	
А	4.28	4.48	
В	6.80	7.00	
d	1.40	1.60	
d1	-	1.50	
Е	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
W	11.70	12.30	

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SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP
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